

DS36950 Quad Differential Bus Transceiver

General Description

The DS36950 is a low power, space-saving quad EIA-485 differential bus transceiver especially suited for high speed, parallel, multipoint, computer I/O bus applications. A compact 20-pin surface mount PLCC package provides high transceiver integration and a very small PC board footprint.

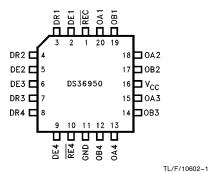
Timing uncertainty across an interface using multiple devices, a typical problem in a parallel interface, is specified—minimum and maximum propagation delay times are guaranteed.

Six devices can implement a complete IPI master or slave interface. Three transceivers in a package are pinned out for connection to a parallel databus. The fourth transceiver, with the flexibility provided by its individual enables, can serve as a control bus transceiver.

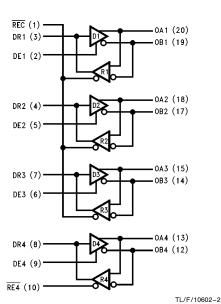
Features

- Pinout for IPI interface
- Compact 20-pin PLCC package
- Meets EIA-485 standard for multipoint bus transmission
- Greater than 60 mA source/sink
- Thermal Shutdown Protection

Pinout and Logic Diagram



Order Number DS36950 See NS Package Number V20A



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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage 7V Control Input Voltage $V_{CC} + 0.5V$ Driver Input Voltage $V_{CC} + 0.5V$ Driver Output Voltage/Receiver Input Voltage -10V to +15V Receiver Output Voltage 5.5V

Recommended Operating Conditions

Lead Temp. (Soldering 4 Sec.)

Continuous Power Dissipation @ 25°C

Derate V Package 13.9 mW/°C above 25°C

V Package

Storage Temp. Range

Supply Voltage, V_{CC} 4.75V to 5.25V Bus Voltage -7V to +12V Operating Free Air Temp. (T_A) 0°C to +70°C

1.73W

260°C

-65°C to +150°C

Electrical Characteristics

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified (Note 2)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
DRIVER C	HARACTERISTICS					
V _{ODL}	Differential Driver Output Voltage (Full Load)	$I_L = 60 \text{ mA}$ $V_{CM} = 0V$	1.5	1.9		V
V _{OD}	Differential Driver Output	$R_L = 100\Omega \text{ (EIA-422)}$	2.0	3.5		٧
	Voltage (Termination Load)	$R_L = 54\Omega$ (EIA-485)	1.5	3.2		٧
ΔIV _{OD} I	Change in Magnitude of Driver Differential Output Voltage for Complementary Output States	$R_L = 54\Omega \text{ or } 100\Omega$ (Note 4) (Figure 1) (EIA-485)			0.2	٧
V _{OC}	Driver Common Mode Output Voltage (Note 5)	$R_L = 54\Omega$ (Figure 1) (EIA-485)			3.0	V
ΔIV _{OC} I	Change in Magnitude of Common Mode Output Voltage	(Note 4) <i>(Figure 1)</i> (EIA-485)			0.2	٧
V_{OH}	Output Voltage HIGH	$I_{OH} = -55 \text{ mA}$	2.7	3.2		V
V_{OL}	Output Voltage LOW	$I_{OL} = 55 \text{mA}$		1.4	1.7	٧
V_{IH}	Input Voltage HIGH		2.0			٧
V_{IL}	Input Voltage LOW				0.8	V
V_{CL}	Input Clamp Voltage	I = -18 mA			-1.5	V
I _{IH}	Input High Current	V _I = 2.4V (Note 3)			20	μΑ
I _{IL}	Input Low Current	V _I = 0.4V (Note 3)			-20	μΑ
losc	Driver Short-Circuit	$V_{O} = -7V$ (EIA-485)		-130	-250	mA
	Output Current (Note 9)	$V_{O} = 0V$ (EIA-422)		-90	-150	mA
	(Note 9)	$V_{O} = +12V$ (EIA-485)		130	250	mA
RECEIVER	RCHARACTERISTICS					
I _{OSR}	Short Circuit Output Current	V _O = 0V (Note 9)	-15	-28	-75	mA
loz	TRI-STATE® Output Current	$V_{O} = 0.4V \text{ to } 2.4V$			20	μΑ
V_{OH}	Output Voltage High	$V_{ID} = 0.20V, I_{OH} = -0.4 \text{ mA}$	2.4	3.0		٧
V_{OL}	Output Voltage Low	$V_{ID} = -0.20V, I_{OL} = 4 \text{ mA}$		0.35	0.5	٧
V _{TH}	Differential Input High Threshold Voltage	$V_{O} = V_{OH}, I_{O} = -0.4 \text{ mA}$ (EIA-422/485)		0.03	0.20	٧
V _{TL}	Differential Input Low Threshold Voltage (Note 6)	$V_{O} = V_{OL}, I_{O} = 4.0 \text{ mA}$ (EIA-422/485)	-0.20	-0.03		٧
V_{HST}	Hysteresis (Note 7)	$V_{CM} = 0V$	35	60		mV

Electrical Characteristics (Continued)
Over Supply Voltage and Operating Temperature ranges, unless otherwise specified (Note 2)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DRIVER A	ND RECEIVER CHARACTERIST	ics					
V_{IH}	Enable Input Voltage High			2.0			V
V_{IL}	Enable Input Voltage Low					0.8	V
V_{CL}	Enable Input Clamp Voltage	I = -18 mA				-1.5	V
I _{IN}	Line Input Current	Other Input = 0V	$V_I = +12V$		0.5	1	mA
	(Note 8)		$V_I = -7V$		-0.45	-0.8	mA
I _{IH}	Enable Input Current High	V _{OH} = 2.4V	RE4 or DE			20	μΑ
			REC			60	μΑ
I _{IL}	Enable Input Current Low	$V_{OL} = 0.4V$	RE4 or DE			-20	μΑ
			REC			-60	μΑ
Icc	Supply Current (Note 10)	No Load, Outputs Enabled			75	90	mA
I _{CCZ}	Supply Current (Note 10)	No Load, Outputs Disabled			50	70	mA

Switching CharacteristicsOver Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Conditions			Тур	Max	Units
DRIVER SI	NGLE-ENDED CHARACTERISTICS					
t _{PZH}	$R_L = 110\Omega$ (Figure 4)			35	40	ns
t _{PZL}	$R_L = 110\Omega$ (Figure 5)			25	40	ns
t _{PHZ}	$R_L = 110\Omega$ (Figure 4)			15	25	ns
t _{PLZ}	$R_L = 110\Omega$ (Figure 5)			35	40	ns
DRIVER DI	FFERENTIAL CHARACTERISTICS					
t _R , t _F	Rise & Fall Time	$R_L = 54\Omega$		13	16	ns
t _{PLHD}	Differential Propagation	$C_L = 50 pF$	9	15	19	ns
t _{PHLD}	Delays (Note 15)	C _D = 15 pF (<i>Figures 3, 8</i>)	9	15	19	ns
t _{SKD}	t _{PLHD} - t _{PHLD} Differential Skew			3	6	ns

Switching Characteristics (Continued)
Over Supply Voltage and Operating Temperature ranges, unless otherwise specified

Symbol	Conditions		Min	Тур	Max	Units
RECEIVER	CHARACTERISTICS					
t _{PLHD}	Differential Propagation Delays C _L = 15 pF, V _{CM} = 1.5V <i>(Figure 6)</i>		9	14	19	ns
t _{PHLD}			9	14	19	ns
t _{SKD}	t _{PLHD} - t _{PHLD} Differential Receiver Skew			1	3	ns
t_{ZH}	Output Enable Time to High Level	C _L = 15 pF (Figure 7)		15	22	ns
t _{ZL}	Output Enable Time to Low Level			20	30	ns
t _{HZ}	Output Disable Time from High Level			10	17	ns
t _{LZ}	Output Disable Time from Low Level			17	25	ns

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Current into device pins is define as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise

Note 3: I_{IH} and I_{IL} includes driver input current and receiver TRI-STATE leakage current.

 $\textbf{Note 4:} \ \Delta \text{IV}_{OD} \text{I and } \Delta \text{IV}_{OC} \text{I are changes in magnitude of V}_{OD} \ \text{and V}_{OC}, \ \text{respectively, that occur when the input changes state.}$

Note 5: In EIA Standards EIA-422 and EIA-485, VOC, which is the average of the two output voltages with respect to ground, is called output offset voltage, VOS.

Note 6: Threshold parameter limits specified as an algebraic value rather than by magnitude.

Note 7: Hysteresis defined as $V_{HST} = V_{TH} - V_{TL}$.

Note 8: I_{IN} includes the receiver input current and driver TRI-STATE leakage current.

Note 9: Short one output at a time.

Note 10: Total package supply current.

Note 11: All typicals are given for $V_{CC}=5.0V$ and $T_{A}=25^{\circ}C$.

Parameter Measurement Information

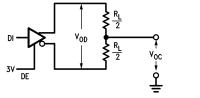


FIGURE 1. Driver $V_{\mbox{\scriptsize OD}}$ and $V_{\mbox{\scriptsize OC}}$

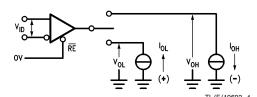
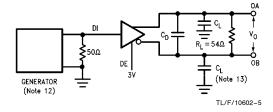
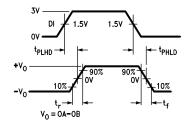


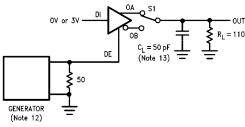
FIGURE 2. Receiver V_{OH} and V_{OL}



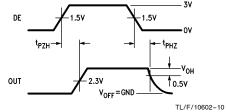


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FIGURE 3. Driver Differential Propagation Delay and Transition Timing



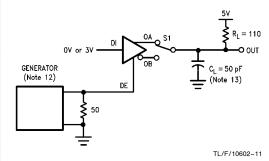
TL/F/10602-9

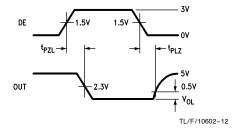


S1 to OA for DI = 3VS1 to OB for DI = 0V

FIGURE 4. Driver Enable and Disable Timing ($t_{\mbox{\scriptsize PZH}}, t_{\mbox{\scriptsize PHZ}}$)

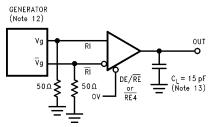
Parameter Measurement Information (Continued)

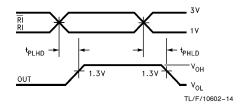




S1 to OA for DI = 0V S1 to OB for DI = 3V

FIGURE 5. Driver Enable and Disable Timing (t_{PZL} , t_{PLZ})

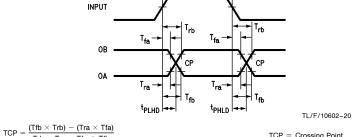




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FIGURE 6. Receiver Differential Propagation Delay Timing

Parameter Measurement Information (Continued) -00UT GENERATOR (Note 12) 5 k (Note 14) (Note 13) 50 TL/F/10602-15 3٧ 3V RE 1.5٧ 1.5V GND t_{PZH} t_{PZL}-4.5V 1.5٧ S1 1.5V S2 OPEN 1.5٧ 0UT - 1.5V GND S2 CLOSED S3 OPEN v_{OL} S3 CLOSED TL/F/10602-16 TL/F/10602-17 3٧ 3٧ RE GND GND – t_{PHZ} 1.37 VOH 0.57 0UT S1 -1.5V S2 CLOSED S1 1.5V ‡ 0.5V V_{OL} · V_{OL} 1.3V S2 CLOSED S3 CLOSED TL/F/10602-18 S3 CLOSED TL/F/10602-19 FIGURE 7. Receiver Enable and Disable Timing INPUT T_{rb} T_{rb} Tfa T_{fa}



TCP = Crossing Point Trb - Tra - Tfa + Tfb

Tra, Trb, Tfa, and Tfb are propagation delay measurements to the 20% and 80% levels.

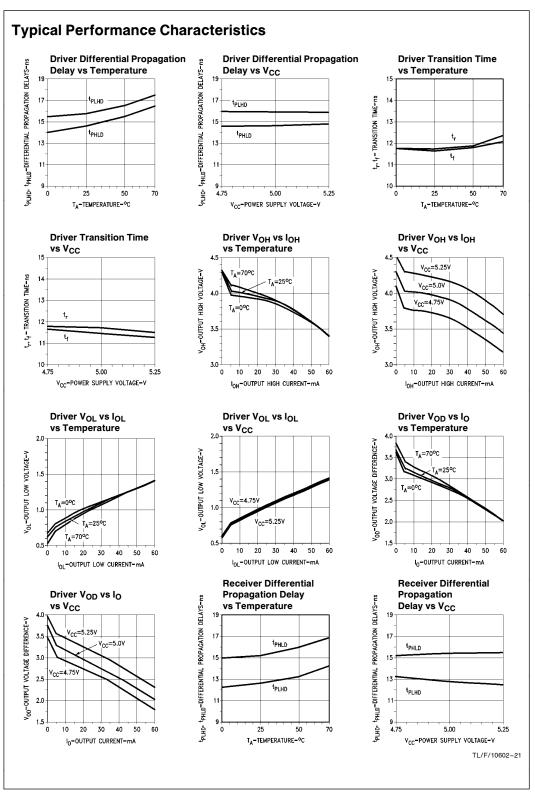
FIGURE 8. Propagation Delay Timing for Calculation of Driver Differential Propagation Delays

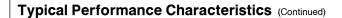
Note 12: The input pulse is supplied by a generator having the following characteristics: $_f=$ 1.0 MHz, 50% Duty Cycle, t_f and $t_r<$ 6.0 ns, $Z_O=50\Omega$

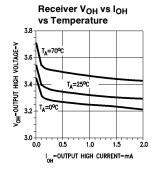
Note 13: C_L includes probe and stray capacitance.

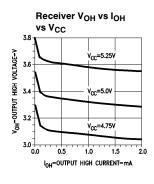
Note 14: Diodes are 1N916 or equivalent.

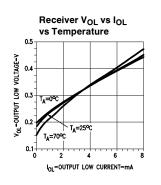
Note 15: Differential propagation delays are calculated from single-ended propagation delays measured from driver input to the 20% and 80% levels on the driver outputs (See Figure 8).

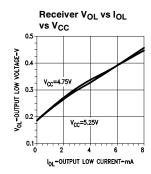


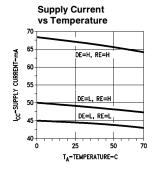


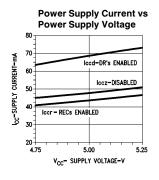


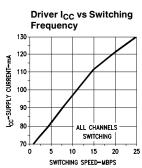








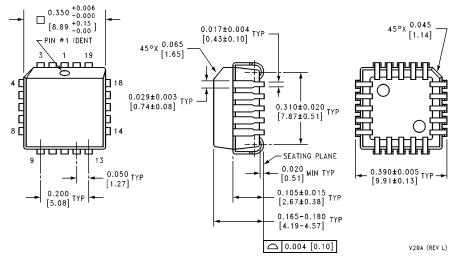




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Physical Dimensions inches (millimeters)

Lit. # 103340



Order Number DS36950 NS Package Number V20A

LIFE SUPPORT POLICY

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